# NSN 5961-01-067-3031

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## **Inclosure Material:**

Ceramic and metal

## **Overall Length:**

1.3 millimeters

# **Overall Diameter:**

2.5 millimeters

## **End Application:**

485I tacs

# Internal Configuration:

Junction contact

## **Mounting Method:**

Press fit

## **Features Provided:**

Hermetically sealed case

## Criticality Code Justification:

Feat

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

25.0 collector to base voltage/static/emitter open and 16.0 collector to emitter voltage/static/base open and 1.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

30.00 milliamperes source cutoff current

# **Power Rating Per Characteristic:**

400.0 milliwatts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Weapon system essential; junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 tab, solder lug and 2 ribbon

### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

No

Fiig:

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